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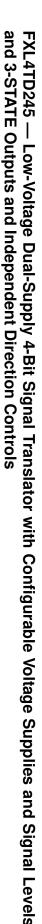
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August 2009

FAIRCHILD

FXL4TD245

Low-Voltage Dual-Supply 4-Bit Signal Translator with Configurable Voltage Supplies and Signal Levels and 3-STATE Outputs and Independent Direction Controls

Features

- Bi-directional interface between any 2 levels from 1.1V to 3.6V
- Fully configurable: inputs track V_{CC} level
- Non-preferential power-up sequencing; either V_{CC} may be powered-up first
- Outputs remain in 3-STATE until active V_{CC} level is reached
- Outputs switch to 3-STATE if either V_{CC} is at GND
- Power-off protection
- Control inputs $(T/\overline{R}_n, \overline{OE})$ levels are referenced to V_{CCA} voltage
- Packaged in 16-terminal DQFN (2.5mm x 3.5mm) and 16-terminal MicroMLP (1.8mm x 2.6mm)
- ESD protections exceeds:
 - 4kV HBM ESD (per JESD22-A114 & Mil Std 883e 3015.7)
 - 8kV HBM I/O to GND ESD (per JESD22-A114 & Mil Std 883e 3015.7)
 - 1kV CDM ESD (per ESD STM 5.3)
 - 200V MM ESD (per JESD22-A115 & ESD STM5.2)

General Description

The FXL4TD245 is a configurable 4-bit dual-voltagesupply translator designed for both uni-directional and bi-directional voltage translation between two logic levels. The device allows translation between voltages as high as 3.6V to as low as 1.1V. The A port tracks the V_{CCA} level, and the B port tracks the V_{CCB} level. This allows for bi-directional voltage translation over a variety of voltage levels: 1.2V, 1.5V, 1.8V, 2.5V, and 3.3V.

The device remains in 3-STATE until both V_{CC}s reach active levels allowing either V_{CC} to be powered-up first. Internal power down control circuits place the device in 3-STATE if either V_{CC} is removed.

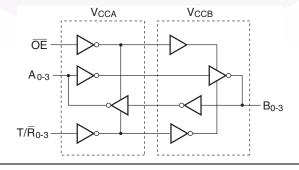
The Transmit/Receive (T/\overline{R}) inputs independently determine the direction of data through each of the four bits. The \overline{OE} input, when HIGH, disables both the A and B Ports by placing them in a 3-STATE condition. The FXL4TD245 is designed so that the control pins (T/ \overline{R} and \overline{OE}) are supplied by V_{CCA}.

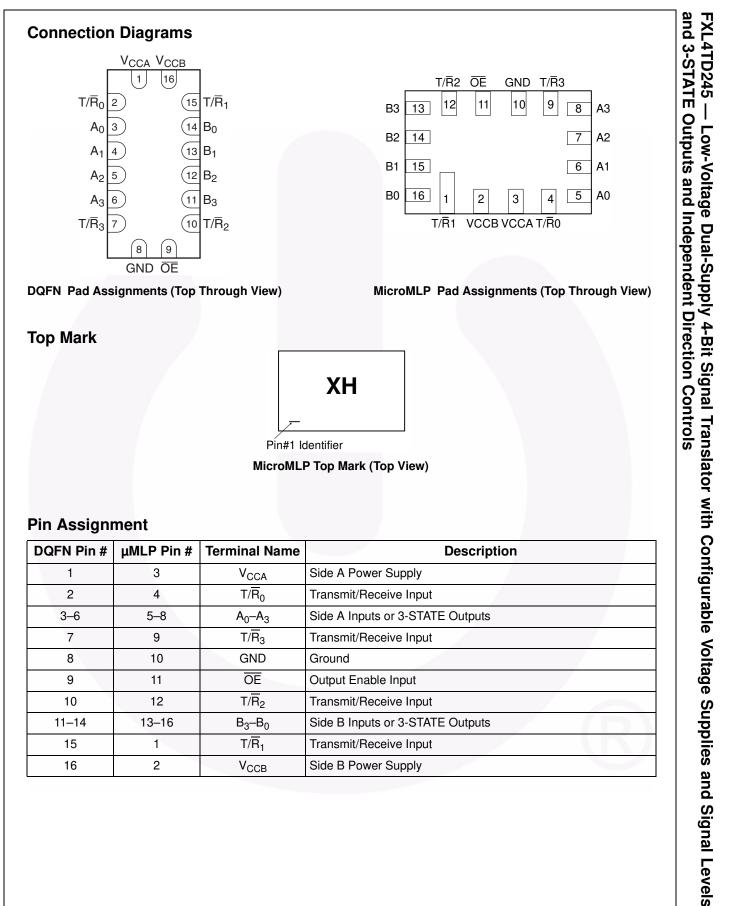
Ordering Information

Order Number	Package Number	Eco Status	Package Description
FXL4TD245BQX	MLP016E		16-Terminal Depopulated Quad Very-Thin Flat Pack, No Leads (DQFN), JEDEC MO-241, 2.5mm x 3.5mm
FXL4TD245UMX	UMLP16A		16-Terminal Quad, Ultrathin, Molded Leadless Package (UMLP), 1.8mm x 2.6mm, 0.4mm Pitch

🕖 For Fairchild's definition of "green" Eco Status, please visit: <u>http://www.fairchildsemi.com/company/green/rohs_green.html</u>.

Functional Diagram





www.fairchildsemi.com

Truth Table

		Inputs	5		
OE	T/\overline{R}_0	T/R ₁	T/\overline{R}_2	T/\overline{R}_3	Outputs
L	L	Х	Х	Х	B0 Data to A0 Output
L	Н	Х	Х	Х	A0 Data to B0 Output
L	Х	L	Х	Х	B1 Data to A1 Output
L	Х	Н	Х	Х	A1 Data to B1 Output
L	Х	Х	L	Х	B2 Data to A2 Output
L	Х	Х	н	Х	A2 Data to B2 Output
L	Х	Х	Х	L	B3 Data to A3 Output
L	Х	х	Х	Н	A3 Data to B3 Output
Н	Х	Х	Х	Х	3-State

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

Power-Up/Power-Down Sequencing

FXL translators offer an advantage in that either V_{CC} may be powered up first. This benefit derives from the chip design. When either V_{CC} is at 0 volts, outputs are in a HIGH-Impedance state. The control inputs (T/ \overline{R}_n and \overline{OE}) are designed to track the V_{CCA} supply. A pull-up resistor tying \overline{OE} to V_{CCA} should be used to ensure that bus contention, excessive currents, or oscillations do not occur during power-up/power-down. The size of the pull-up resistor is based upon the current-sinking capability of the \overline{OE} driver.

The recommended power-up sequence is the following:

- 1. Apply power to either V_{CC} .
- 2. Apply power to the T/\overline{R}_n inputs (Logic HIGH for A-to-B operation; Logic LOW for B-to-A operation) and to the respective data inputs (A Port or B Port). This may occur at the same time as Step 1.
- 3. Apply power to other V_{CC} .
- 4. Drive the \overline{OE} input LOW to enable the device.

The recommended power-down sequence is the following:

- 1. Drive OE input HIGH to disable the device.
- 2. Remove power from either V_{CC} .
- 3. Remove power from other V_{CC} .

Absolute Maximum Ratings

The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Symbol	Parameter	Rating
V _{CCA} , V _{CCB}	Supply Voltage	-0.5V to +4.6V
VI	DC Input Voltage I/O Port A I/O Port B Control Inputs (T/R _n , OE)	-0.5V to +4.6V -0.5V to +4.6V -0.5V to +4.6V
Vo	Output Voltage ⁽¹⁾ Outputs 3-STATE Outputs Active (A _n) Outputs Active (B _n)	-0.5V to +4.6V -0.5V to V _{CCA} + 0.5V -0.5V to V _{CCB} + 0.5V
I _{IK}	DC Input Diode Current @ V _I < 0V	–50mA
I _{ОК}	$ \begin{array}{c} DC \mbox{ Output Diode Current } @ \\ V_O < 0V \\ V_O > V_{CC} \end{array} \end{array} $	–50mA +50mA
I _{OH} / I _{OL}	DC Output Source/Sink Current	-50mA / +50mA
I _{CC}	DC V _{CC} or Ground Current per Supply Pin	±100mA
T _{STG}	Storage Temperature Range	−65°C to +150°C

Recommended Operating Conditions⁽²⁾

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Rating
$V_{\text{CCA}} \text{ or } V_{\text{CCB}}$	Power Supply Operating	1.1V to 3.6V
	Input Voltage Port A Port B Control Inputs (T/R _n , OE)	0.0V to 3.6V 0.0V to 3.6V 0.0V to V _{CCA}
	Output Current in I _{OH} /I _{OL} with V _{CC @} 3.0V to 3.6V 2.3V to 2.7V 1.65V to 1.95V 1.4V to 1.65V 1.1V to 1.4V	±24mA ±18mA ±6mA ±2mA ±0.5mA
T _A	Free Air Operating Temperature	-40°C to +85°C
$\Delta t / \Delta V$	Maximum Input Edge Rate $V_{CCA/B} = 1.1V$ to 3.6V	10ns/V

Notes:

1. I_O Absolute Maximum Rating must be observed.

2. All unused inputs and I/O pins must be held at $V_{\mbox{CCI}}$ or GND.

Symbol	Parameter	Conditions	V _{CCI} (V)	$V_{CCO}(V)$	Min.	Max.	Units
V _{IH}	High Level Input	Data Inputs A _n , B _n	2.7–3.6	1.1–3.6	2.0		V
	Voltage ⁽³⁾		2.3–2.7		1.6		
			1.65–2.3		0.65 x V _{CCI}		
			1.4-1.65		0.65 x V _{CCI}		
			1.1-1.4		0.9 x V _{CCI}		
		Control Pins \overline{OE} , T/ \overline{R}_n	2.7–3.6	1.1–3.6	2.0		
		(Referenced to V _{CCA})	2.3–2.7		1.6		
			1.65–2.3		$0.65 \times V_{CCA}$		
			1.4-1.65		$0.65 \times V_{CCA}$		
			1.1-1.4		0.9 x V _{CCA}		
V _{IL}	Low Level Input	Data Inputs A _n , B _n	2.7–3.6	1.1–3.6		0.8	V
	Voltage ⁽³⁾		2.3–2.7			0.7	
			1.65–2.3			0.35 x V _{CCI}	
			1.4-1.65			0.35 x V _{CCI}	
			1.1-1.4			0.1 x V _{CCI}	
		Control Pins \overline{OE} , T/ \overline{R}_n	2.7–3.6	1.1–3.6		0.8	
	(Referenced to V _{CCA})	2.3–2.7			0.7		
			1.65–2.3			$0.35 \times V_{CCA}$	
			1.4-1.65			$0.35 \times V_{CCA}$	
			1.1-1.4			0.1 x V _{CCA}	
V _{OH}	High Level Output	$I_{OH} = -100 \mu A$	1.1–3.6	1.1–3.6	V _{CC0} -0.2		V
	Voltage ⁽⁴⁾	$I_{OH} = -12mA$	2.7	2.7	2.2		
		$I_{OH} = -18 mA$	3.0	3.0	2.4		
		$I_{OH} = -24mA$	3.0	3.0	2.2		
		$I_{OH} = -6mA$	2.3	2.3	2.0		1
		$I_{OH} = -12mA$	2.3	2.3	1.8		
		$I_{OH} = -18 \text{mA}$	2.3	2.3	1.7		
		$I_{OH} = -6mA$	1.65	1.65	1.25		
		$I_{OH} = -2mA$	1.4	1.4	1.05		
		$I_{OH} = -0.5 \text{mA}$	1.1	1.1	0.75 x V _{CC0}		
V _{OL}	Low Level Output	$I_{OL} = 100 \mu A$	1.1–3.6	1.1- 3.6		0.2	V
	Voltage ⁽⁴⁾	$I_{OL} = 12mA$	2.7	2.7		0.4	
		$I_{OL} = 18 \text{mA}$	3.0	3.0		0.4	
		$I_{OL} = 24mA$	3.0	3.0		0.55	
		I _{OL} =12mA	2.3	2.3		0.4	
		$I_{OL} = 18 \text{mA}$	2.3	2.3		0.6	1
		I _{OL} = 6mA	1.65	1.65		0.3	1
		$I_{OL} = 2mA$	1.4	1.4		0.35	1
		I _{OL} = 0.5mA	1.1	1.1		0.3 x V _{CC0}	1

Symbol	Parameter	Conditions	V _{CCI} (V)	$V_{CCO}(V)$	Min.	Max.	Units
I	Input Leakage Current. Control Pins	V _I = V _{CCA} or GND	1.1–3.6	3.6		±1.0	μA
I _{OFF}	Power Off Leak-	A_n , V_l or $V_O = 0V$ to 3.6V	0	3.6		±10.0	μA
	age Current	B_n , V_l or $V_O = 0V$ to 3.6V	3.6	0		±10.0	
I _{OZ}	3-STATE Output	$A_n, B_n \qquad \overline{OE} = V_{IH}$	3.6	3.6		±10.0	μA
	Leakage ⁽⁵⁾ 0 ≤ V _O ≤ 3.6V	B_n , $\overline{OE} = Don't Care$	0	3.6		+10.0	
	$V_{I} = V_{IH} \text{ or } V_{IL}$	A_n , $\overline{OE} = Don't Care$	3.6	0		+10.0	
I _{CCA/B}	Quiescent Supply Current ⁽⁶⁾	$V_I = V_{CCI}$ or GND; $I_O = 0$	1.1–3.6	1.1–3.6		20.0	μA
I _{CCZ}	Quiescent Supply Current ⁽⁶⁾	$V_I = V_{CCI}$ or GND; $I_O = 0$	1.1–3.6	1.1–3.6		20.0	μA
I _{CCA}	Quiescent Supply	$V_I = V_{CCA}$ or GND; $I_O = 0$	0	1.1–3.6		-10.0	μA
	Current	$V_I = V_{CCA}$ or GND; $I_O = 0$	1.1–3.6	0		10.0	μA
I _{CCB}	Quiescent Supply	$V_I = V_{CCB}$ or GND; $I_O = 0$	1.1–3.6	0		-10.0	μA
	Current	$V_I = V_{CCB}$ or GND; $I_O = 0$	0	1.1–3.6		10.0	μA
∆I _{CCA/B}	Increase in I_{CC} per Input; Other Inputs at V_{CC} or GND	V _{IH} = 3.0	3.6	3.6		500	μA

DC Electrical Characteristics (Continued)

Notes:

3. V_{CCI} = the V_{CC} associated with the data input under test.

4. V_{CCO} = the V_{CC} associated with the output under test.

5. Don't Care = Any valid logic level.

6. Reflects current per supply, V_{CCA} or V_{CCB} .

FXL4TD245 — Low-Voltage Dual-Supply 4-Bit Signal Translator with Configurable Voltage Supplies and Signal Levels and 3-STATE Outputs and Independent Direction Controls

AC Electrical Characteristics

$V_{CCA} = 3.0V$ to 3.6V

					Τ _Α	= -40°0	C to +8	5°C				
			св = о 3.6V	V _{C0} 2.3V t	св = o 2.7V	1.65	св = V to 95V		св = о 1.6V		св = о 1.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.2	3.5	0.3	3.9	0.5	5.4	0.6	6.8	1.4	22.0	ns
	Propagation Delay B to A	0.2	3.5	0.2	3.8	0.3	4.0	0.5	4.3	0.8	13.0	
t _{PZH} , t _{PZL}	Output Enable OE to B	0.5	4.0	0.7	4.4	1.0	5.9	1.0	6.4	1.5	17.0	ns
	Output Enable OE to A	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	
t _{PHZ} , t _{PLZ}	Output Disable OE to B	0.2	3.8	0.2	4.0	0.7	4.8	1.5	6.2	2.0	17.0	ns
	Output Disable OE to A	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	

$V_{\mbox{\scriptsize CCA}}=2.3V$ to 2.7V

					Τ _Α	= -40°0	C to +8	5°C				
			св = о 3.6V		св = o 2.7V	1.65	св = 5V to 95V		св = о 1.6V	V _{CC} 1.1V te	св = о 1.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.2	3.8	0.4	4.2	0.5	5.6	0.8	6.9	1.4	22.0	ns
	Propagation Delay B to A	0.3	3.9	0.4	4.2	0.5	4.5	0.5	4.8	1.0	7.0	
t _{PZH} , t _{PZL}	Output Enable OE to B	0.6	4.2	0.8	4.6	1.0	6.0	1.0	6.8	1.5	17.0	ns
	Output Enable OE to A	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	
t _{PHZ} , t _{PLZ}	Output Disable OE to B	0.2	4.1	0.2	4.3	0.7	4.8	1.5	6.7	2.0	17.0	ns
	Output Disable OE to A	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	

V_{CCA} = 1.65V to 1.95V

					Τ _Α	= - 40 °(C to +8	5°C				
			св = о 3.6V		св ⁼ o 2.7V		св = V to 5V		св = о 1.6V		св = о 1.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.3	4.0	0.5	4.5	0.8	5.7	0.9	7.1	1.5	22.0	ns
	Propagation Delay B to A	0.5	5.4	0.5	5.6	0.8	5.7	1.0	6.0	1.2	8.0	
t _{PZH} , t _{PZL}	Output Enable OE to B	0.6	5.2	0.8	5.4	1.2	6.9	1.2	7.2	1.5	18.0	ns
	Output Enable OE to A	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	D
t _{PHZ} , t _{PLZ}	Output Disable OE to B	0.2	5.1	0.2	5.2	0.8	5.2	1.5	7.0	2.0	17.0	ns
	Output Disable OE to A	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	

and 3-STATE Outputs and Independent Direction Controls FXL4TD245 — Low-Voltage Dual-Supply 4-Bit Signal Translator with Configurable Voltage Supplies and Signal Levels

AC Electrical Characteristics (Continued)

$V_{CCA} = 1.4V$ to 1.6V

					Τ _Α	= -40°0	C to +8	5°C				
		V _{CC} 3.0V t	св = о 3.6V	V _{CC} 2.3V t	св = о 2.7V		св = V to 5V	V _{CC} 1.4V t	св = о 1.6V		св = о 1.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.5	4.3	0.5	4.8	1.0	6.0	1.0	7.3	1.5	22.0	ns
	Propagation Delay B to A	0.6	6.8	0.8	6.9	0.9	7.1	1.0	7.3	1.3	9.5	
t _{PZH} , t _{PZL}	Output Enable OE to B	1.1	7.5	1.1	7.6	1.3	7.7	1.4	7.9	2.0	20.0	ns
	Output Enable OE to A	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	
t _{PHZ} , t _{PLZ}	Output Disable OE to B	0.4	6.1	0.4	6.2	0.9	6.2	1.5	7.5	2.0	18.0	ns
	Output Disable OE to A	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	

V_{CCA} = 1.1V to 1.3V

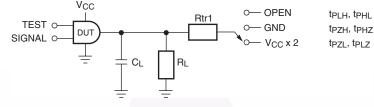
					Τ _Α	= -40°(C to +8	5°C				
		V _{CC} 3.0V te	св = о 3.6V	V _{C0} 2.3V t	св ⁼ o 2.7V	1.65	св = V to 5V		св = о 1.6V		св = о 1.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.8	13.0	1.0	7.0	1.2	8.0	1.3	9.5	2.0	24.0	ns
	Propagation Delay B to A	1.4	22.0	1.4	22.0	1.5	22.0	1.5	22.0	2.0	24.0	
t _{PZH} , t _{PZL}	Output Enable OE to B	1.0	12.0	1.0	9.0	2.0	10.0	2.0	11.0	2.0	24.0	ns
	Output Enable OE to A	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	
t _{PHZ} , t _{PLZ}	Output Disable OE to B	1.0	15.0	0.7	7.0	1.0	8.0	2.0	10.0	2.0	20.0	ns
	Output Disable OE to A	2.0	15.0	2.0	12.0	2.0	12.0	2.0	12.0	2.0	12.0	

Capacitance

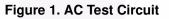
			$T_A = +25^{\circ}C$	
Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance Control Pins (\overline{OE} , T/ \overline{R})	$V_{CCA} = V_{CCB} = 3.3V$, $V_I = 0V$ or $V_{CCA/B}$	4.0	pF
C _{I/O}	Input/Output Capacitance An, Bn Ports	$V_{CCA} = V_{CCB} = 3.3V$, $V_I = 0V$ or $V_{CCA/B}$	5.0	pF
C _{PD}	Power Dissipation Capacitance	$V_{CCA} = V_{CCB} = 3.3V$, $V_I = 0V$ or V_{CC} , F = 10MHz	20.0	pF

and 3-STATE Outputs and Independent Direction Controls FXL4TD245 — Low-Voltage Dual-Supply 4-Bit Signal Translator with Configurable Voltage Supplies and Signal Levels

AC Loading and Waveforms

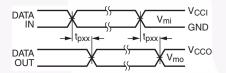


Test	Switch
t _{PLH} , t _{PHL}	OPEN
t _{PLZ} , t _{PZL}	$ \begin{array}{l} V_{CCO} \ x \ 2 \ at \ V_{CCO} = 3.3 \pm 0.3 \text{V}, \ 2.5 \text{V} \pm 0.2 \text{V}, \\ 1.8 \text{V} \pm 0.15 \text{V}, \ 1.5 \text{V} \pm 0.1 \text{V}, \ 1.2 \text{V} \pm 0.1 \text{V} \end{array} $
t _{PHZ} , t _{PZH}	GND



AC Load Table

V _{cco}	CL	RL	Rtr1
$1.2V\pm0.1V$	15pF	2kΩ	2kΩ
$1.5V\pm0.1V$	15pF	2kΩ	2kΩ
$1.8V \pm 0.15V$	15pF	2kΩ	2kΩ
$2.5V\pm0.2V$	15pF	2kΩ	2kΩ
$3.3V\pm0.3V$	15pF	2kΩ	2kΩ



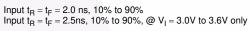
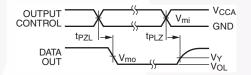
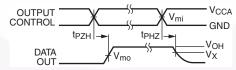


Figure 2. Waveform for Inverting and Non-Inverting Functions



Input $t_R=t_F=2.0$ ns, 10% to 90% Input $t_R=t_F=2.5 ns,$ 10% to 90%, @ VI = 3.0V to 3.6V only

Figure 3. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic



Input $t_R = t_F = 2.0$ ns, 10% to 90%

Input $t_{R} = t_{F} = 2.5$ ns, 10% to 90%, @ V_I = 3.0V to 3.6V only

Figure 4. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

Symbol	V _{cc}				
	$\textbf{3.3V} \pm \textbf{0.3V}$	$\textbf{2.5V} \pm \textbf{0.2V}$	$\textbf{1.8V} \pm \textbf{0.15V}$	$\textbf{1.5V} \pm \textbf{0.1V}$	$\textbf{1.2V} \pm \textbf{0.1V}$
V _{mi}	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2
V _{mo}	$V_{CCO}/2$	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2
V _X	V _{OH} -0.3V	V _{OH} -0.15V	V _{OH} -0.15V	V _{OH} -0.1V	V _{OH} -0.1V
V _Y	V _{OL} +0.3V	V _{OL} +0.15V	V _{OL} +0.15V	V _{OL} +0.1V	V _{OL} +0.1V

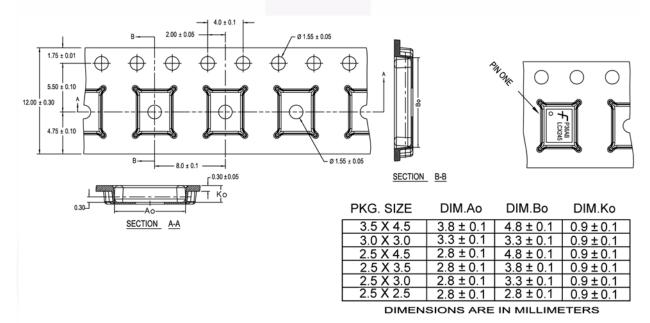
For V_{mi} : $V_{CCI} = V_{CCA}$ for Control Pins T/ \overline{R} and \overline{OE} , or $V_{CCA}/2$

Tape and Reel Specification

Tape Format for DQFN 10

Package Designator	Tape Section	Number Cavities	Cavity Status	Cover Tape Status
BQX	Leader (Start End)	125 (typ)	Empty	Sealed
-	Carrier	2500/3000	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed

Tape Dimensions millimeters



NOTES: unless otherwise specified

1. Cummulative pitch for feeding holes and cavities (chip pockets) not to exceed 0.008[0.20] over 10 pitch span.

2. Smallest allowable bending radius.

3. Thru hole inside cavity is centered within cavity.

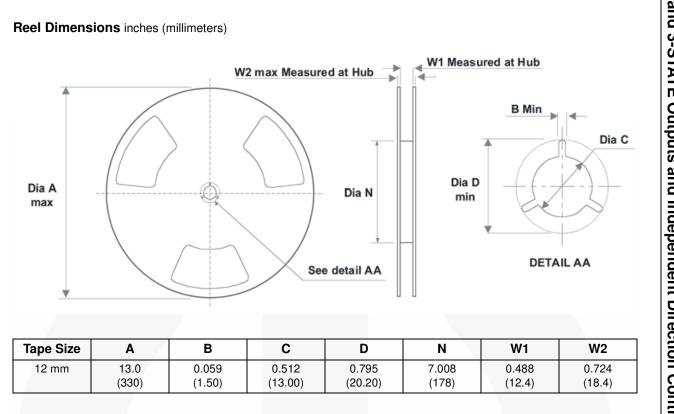
4. Tolerance is ±0.002[0.05] for these dimensions on all 12mm tapes.

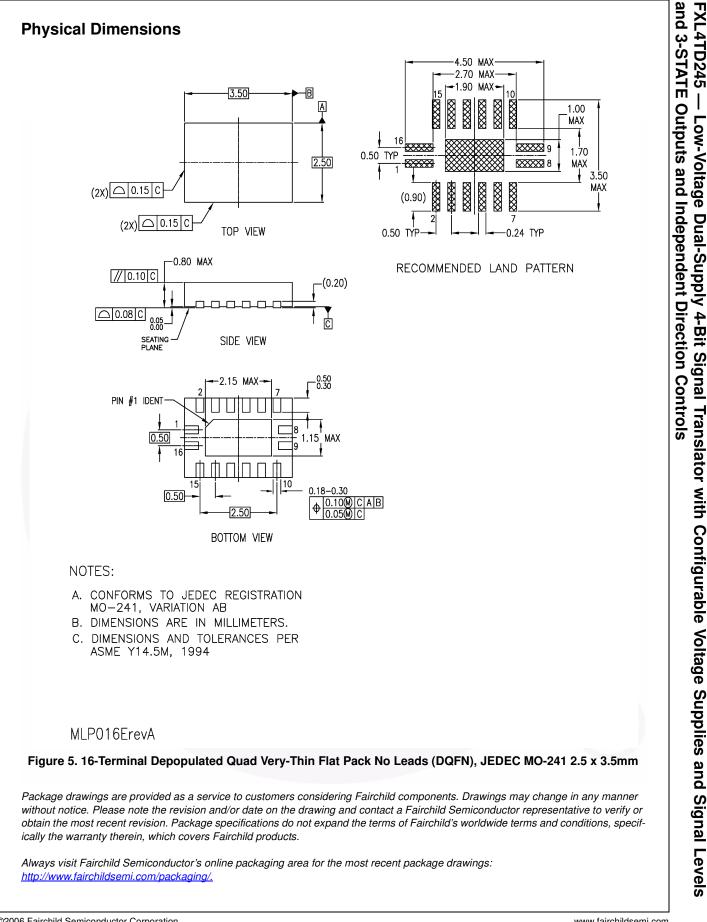
5. Ao and Bo measured on a plane 0.120[0.30] above the bottom of the pocket.

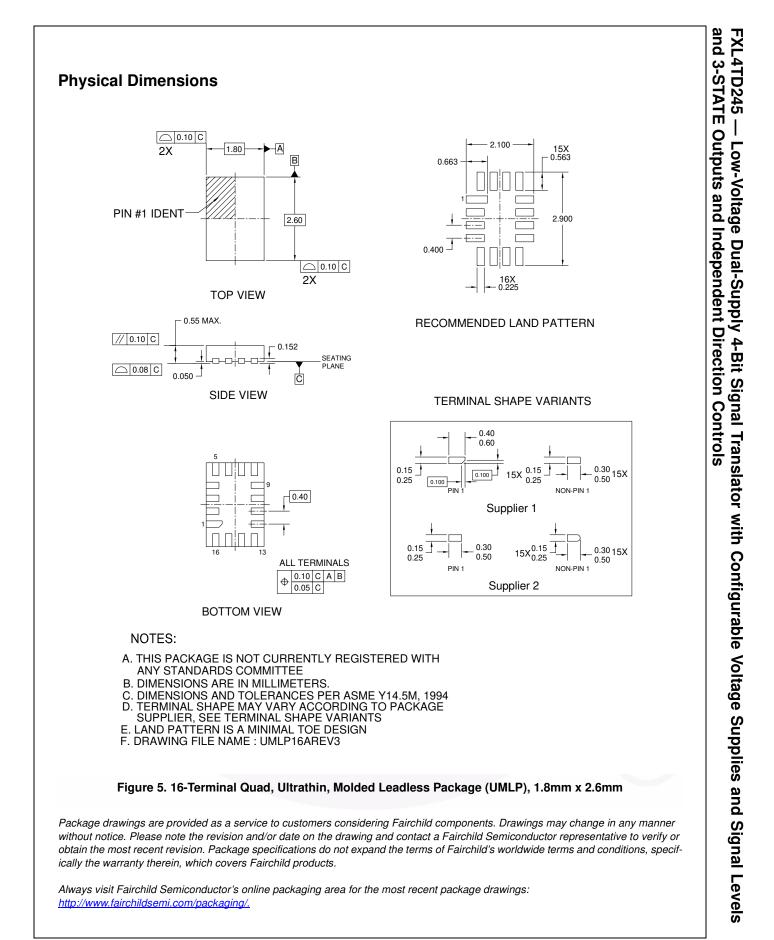
6. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.

7. Pocket position relative to sprocket hole measured as true position of pocket. Not pocket hole.

8. Controlling dimension is millimeter. Diemension in inches rounded.







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FXL4TD245 — Low-Voltage Dual-Supply 4-Bit Signal Translator with Configurable Voltage Supplies and Signal Levels and 3-STATE Outputs and Independent Direction Controls

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